

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	1	10/606859	US-PGPUB; USPAT	OR	ON	2005/12/12 08:52
L3	857	501/137,138,139.ccls.	US-PGPUB; USPAT	OR	ON	2005/12/12 08:53
L4	40	3 and memory	US-PGPUB; USPAT	OR	ON	2005/12/12 09:04
L5	2	4 and (hf or "hfo.sub.2")	US-PGPUB; USPAT	OR	ON	2005/12/12 09:05
L6	76	3 and (hf or "hfo.sub.2")	US-PGPUB; USPAT	OR	ON	2005/12/12 09:46
L7	2	"2001351828"	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:20
L8	95	memory and dielectric and (hf or "hfo.sub.2")	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:22
L9	7	8 and (ba or bao)	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:20
L10	7584	memory and dielectric and (hf or "hfo.sub.2")	US-PGPUB; USPAT	OR	ON	2005/12/12 09:34
L11	864	10 and (ba or bao)	US-PGPUB; USPAT	OR	ON	2005/12/12 09:27
L12	0	"68597174"	US-PGPUB; USPAT	OR	ON	2005/12/12 09:27
L13	1	"6897174"	US-PGPUB; USPAT	OR	ON	2005/12/12 09:31
L15	1	2 and memory	US-PGPUB; USPAT	OR	ON	2005/12/12 09:33
L16	997	memory and dielectric and quaternary	US-PGPUB; USPAT	OR	ON	2005/12/12 09:38
L17	121	16 and (hf or "hfo.sub.2")	US-PGPUB; USPAT	OR	ON	2005/12/12 09:34
L18	0	501/137-139.ccls. and dielectric and quaternary	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:37
L19	0	501/137-139.ccls. and quaternary	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:37
L20	4	memory and dielectric and quaternary	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:40
L21	0	gbit adj memory adj device.clm.	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:40
L22	2	gbit adj memory adj device	EPO; JPO; DERWENT	OR	ON	2005/12/12 09:40
L23	0	gbit adj memory adj device.clm.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/12 09:41

L24	3	gbit adj memory adj device	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/12 09:41
L25	3339	memory adj device.clm. and dielectric.clm.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/12 09:46
L26	2284	365/149.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/12 09:46
L27	68	26 and (hf or "hfo.sub.2")	US-PGPUB; USPAT	OR	ON	2005/12/12 09:47